

FS50UMJ-03

HIGH-SPEED SWITCHING USE

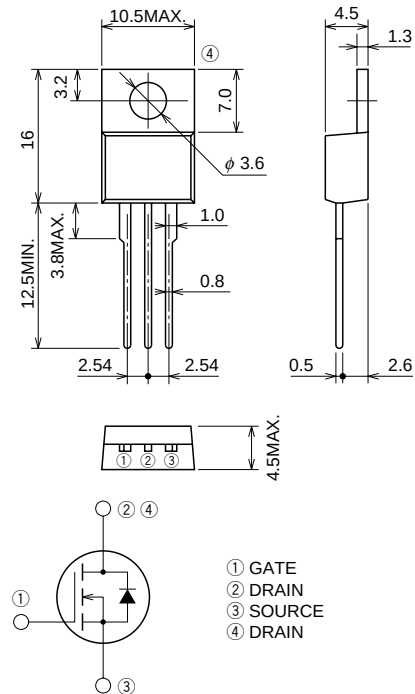
FS50UMJ-03



- 4V DRIVE
- V_{DS} 30V
- $r_{DS(ON)}$ (MAX) 19m Ω
- I_D 50A
- Integrated Fast Recovery Diode (TYP.) 60ns

OUTLINE DRAWING

Dimensions in mm



TO-220

APPLICATION

Motor control, Lamp control, Solenoid control
DC-DC converter, etc.

MAXIMUM RATINGS (Tc = 25°C)

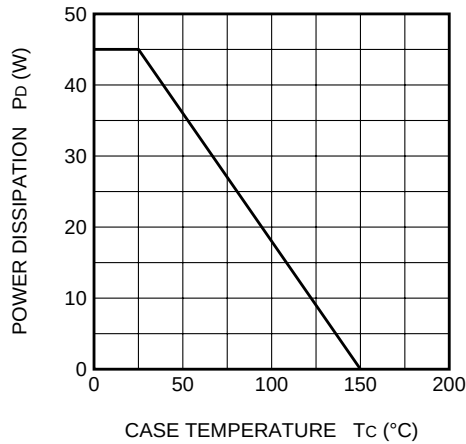
Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	30	V
V_{GS}	Gate-source voltage	$V_{DS} = 0V$	± 20	V
I_D	Drain current		50	A
I_{DM}	Drain current (Pulsed)		200	A
I_{DA}	Avalanche drain current (Pulsed)	$L = 30\mu H$	50	A
I_S	Source current		50	A
I_{SM}	Source current (Pulsed)		200	A
P_D	Maximum power dissipation		45	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	2.0	g

ELECTRICAL CHARACTERISTICS (T_{ch} = 25°C)

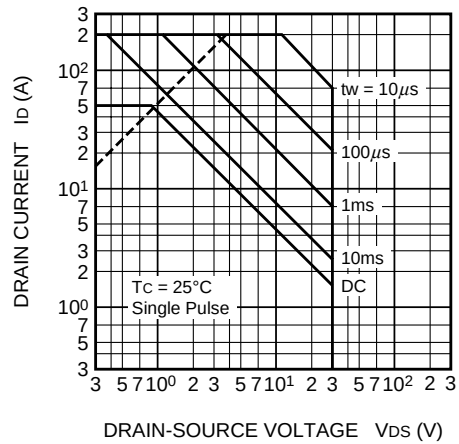
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _{(BR) DSS}	Drain-source breakdown voltage	I _D = 1mA, V _{GS} = 0V	30	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±20V, V _{DS} = 0V	—	—	±0.1	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 30V, V _{GS} = 0V	—	—	0.1	mA
V _{GS(th)}	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	1.0	1.5	2.0	V
r _{DS(on)}	Drain-source on-state resistance	I _D = 25A, V _{GS} = 10V	—	15	19	mΩ
r _{DS(on)}	Drain-source on-state resistance	I _D = 25A, V _{GS} = 4V	—	21	35	mΩ
V _{DS(on)}	Drain-source on-state voltage	I _D = 25A, V _{GS} = 10V	—	0.375	0.475	V
y _{fs}	Forward transfer admittance	I _D = 25A, V _{DS} = 10V	—	28	—	S
C _{iss}	Input capacitance	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	—	1600	—	pF
C _{oss}	Output capacitance		—	500	—	pF
C _{rss}	Reverse transfer capacitance		—	260	—	pF
t _{d(on)}	Turn-on delay time	V _{DD} = 15V, I _D = 25A, V _{GS} = 10V, R _{GEN} = R _{GS} = 50Ω	—	17	—	ns
t _r	Rise time		—	90	—	ns
t _{d(off)}	Turn-off delay time		—	130	—	ns
t _f	Fall time		—	125	—	ns
V _{SD}	Source-drain voltage	I _S = 25A, V _{GS} = 0V	—	1.0	1.5	V
R _{th(ch-c)}	Thermal resistance	Channel to case	—	—	2.78	°C/W
t _{rr}	Reverse recovery time	I _S = 25A, di _S /dt = -50A/μs	—	60	—	ns

PERFORMANCE CURVES

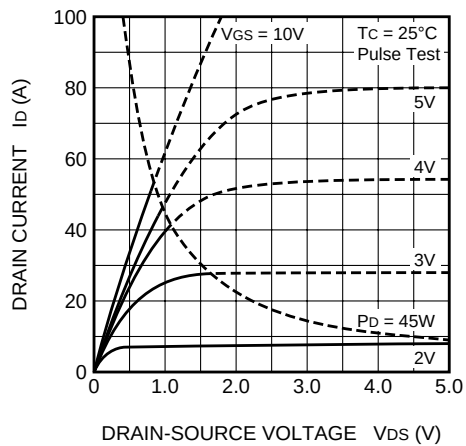
POWER DISSIPATION DERATING CURVE



MAXIMUM SAFE OPERATING AREA



OUTPUT CHARACTERISTICS (TYPICAL)



OUTPUT CHARACTERISTICS (TYPICAL)

